NSN 5961-01-276-2456

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-276-2456 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** Between 0.250 inches and 0.300 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.0 gate to source threshold voltage and 4.5 gate to source threshold voltage **Current Rating Per Characteristic:** 500.00 nanoamperes zero-gate-voltage source current watts and 250.00 microamperes zero-gate-voltage source current megawatts **Maximum Operating Tempurature Per Measurement Point:** 140.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**